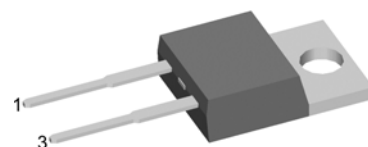
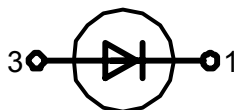


Sonic-FRD

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Single Diode

Part number (Marking on product)

DHG 10 I 600PA



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{RM} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{RM} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package:

- TO-220AC
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

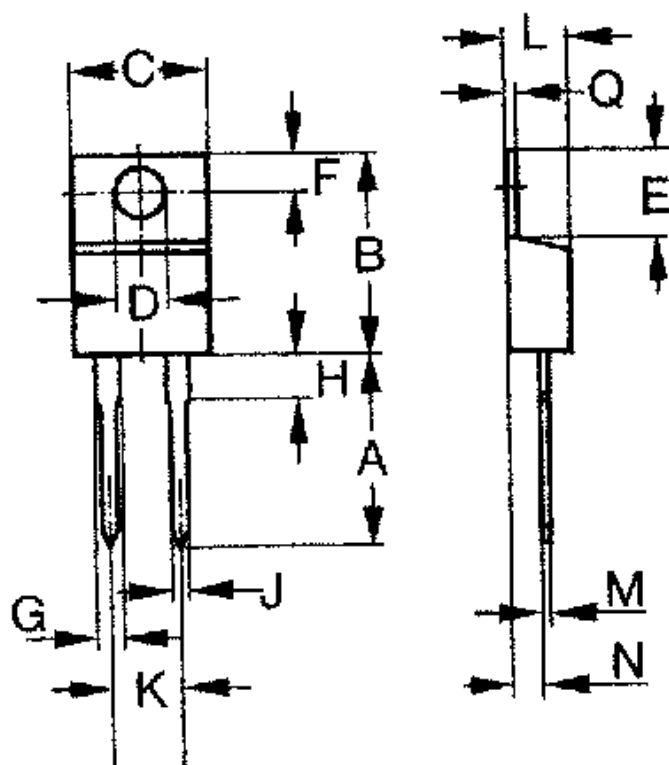
Symbol	Definition	Conditions	min.	typ.	max.	Unit
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25\text{ °C}$			600	V
I_R	reverse current	$V_R = 600\text{ V}$ $T_{VJ} = 25\text{ °C}$ $V_R = 600\text{ V}$ $T_{VJ} = 125\text{ °C}$			15 1.5	μA mA
V_F	forward voltage	$I_F = 10\text{ A}$ $I_F = 20\text{ A}$ $T_{VJ} = 25\text{ °C}$ $I_F = 10\text{ A}$ $I_F = 20\text{ A}$ $T_{VJ} = 125\text{ °C}$			2.35 V 2.20 V	V V
I_{FAV}	average forward current	rectangular, $d = 0.5$ $T_C = 95\text{ °C}$			10	A
V_{FO}	threshold voltage	} for power loss calculation only $T_{VJ} = 150\text{ °C}$			1.20	V
r_F	slope resistance				93	m Ω
R_{thJC}	thermal resistance junction to case				1.80	K/W
T_{VJ}	virtual junction temperature		-55		150	°C
P_{tot}	total power dissipation	$T_C = 25\text{ °C}$			70	W
I_{FSM}	max. forward surge current	$t_p = 10\text{ ms (50 Hz), sine}$ $T_{VJ} = 45\text{ °C}$			100	A
I_{RM}	max. reverse recovery current	$I_F = 10\text{ A};$ $T_{VJ} = 25\text{ °C}$ $T_{VJ} = 125\text{ °C}$		4		A A
t_{rr}	reverse recovery time	$-di_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$ $T_{VJ} = 25\text{ °C}$ $T_{VJ} = 125\text{ °C}$		35		ns ns
C_j	junction capacitance	$V_R = 300\text{ V}; f = 1\text{ MHz}$ $T_{VJ} = 25\text{ °C}$				pF
E_{AS}	non-repetitive avalanche energy	$I_{AS} = \text{A}; L = 100\text{ }\mu\text{H}$ $T_{VJ} = 25\text{ °C}$			tbd	mJ
I_{AR}	repetitive avalanche current	$V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$			tbd	A

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per pin*			35	A
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
M_D	mounting torque		0.4		0.6	Nm
F_C	mounting force with clip		20		60	N
T_{stg}	storage temperature		-55		150	°C
Weight				2		g

* Irms is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Outlines TO-220AC



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	14.73	0.500	0.580
B	14.23	16.51	0.560	0.650
C	9.66	10.66	0.380	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	2.300	0.420
F	2.54	3.42	0.100	0.135
G	1.15	1.77	0.045	0.070
H	-	6.35	-	0.250
J	0.64	0.89	0.025	0.035
K	4.83	5.33	0.190	0.210
L	3.56	4.82	0.140	0.190
M	0.51	0.76	0.020	0.030
N	2.04	2.49	0.080	0.115
Q	0.64	1.39	0.025	0.055

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➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com